

SILICON HYPERABRUPT VARACTOR DIODE

DESCRIPTION:

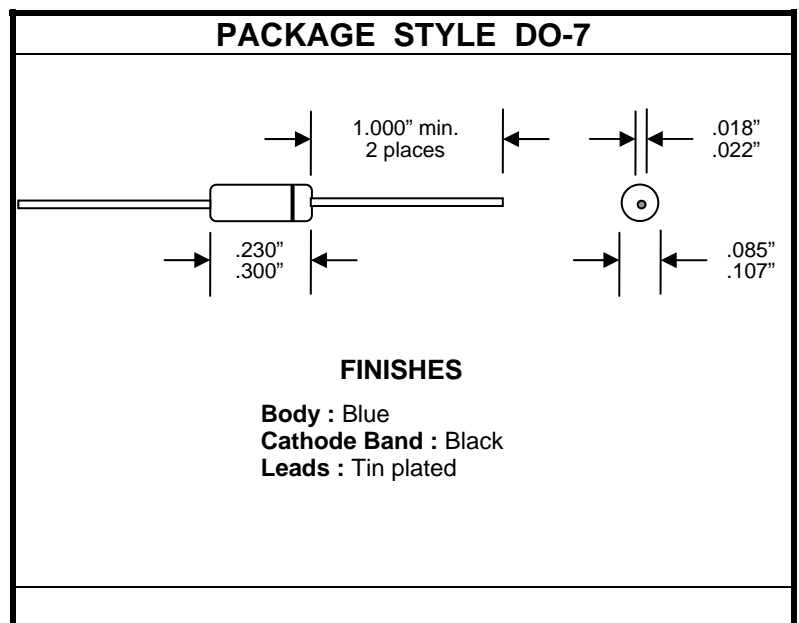
The **DKV6533C** is designed for UHF Filter and Oscillator Applications that Require Octave tuning.

FEATURES:

- $T_R = 4.6$ Min. at $V_R = 3 / 20$ V
- $Q = 450$ Min. at 3 V / 50 MHz
- Hermetic **DO-7** Package

MAXIMUM RATINGS

I_F	50 mA
V_R	22 V
P_{DISS}	250 mW @ $T_C = 25$ °C
T_J	-55 °C to + 125 °C
T_{STG}	-55 °C to +175 °C


CHARACTERISTICS $T_C = 25$ °C

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
V_{BR}	$I_R = 10$ μ A	22			V
I_R	$V_R = 20$ V			100	nA
C_T	$V_R = 3.0$ V	10.5		12.5	pF
	$V_R = 8.0$ V	4.3		5.7	
	$V_R = 20$ V	2.0		2.3	
T_R	$V_R = 3$ & 20 V	4.6		6.3	---
Q	$V_R = 3.0$ V	450			